

HUAXUANYANG ULN2003 Darlington Transistor Array Instructions

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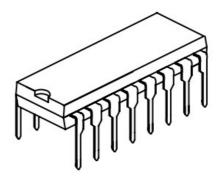
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Product features:

ULN2003 is a 7-way Darlington structure circuit.

The output current of each channel is 500mA, the peak current is 600mA, and the output voltage is 50V. Emitter structure, each channel can be output independently. Should Circuits are often used to drive various loads, such as DC motors, LED display lights, high-power buffers and 5V TTL, CMOS and other general logic circuits, etc.



SOP-16

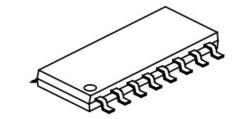


Figure 1 ULN2003 circuit outline diagram

Package form and pin definition

SOP16/DIP16 dual row package form:

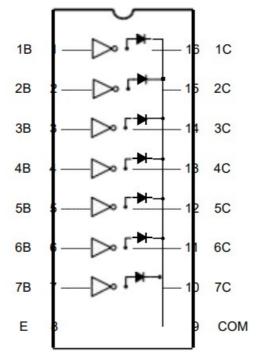


Figure 2ULN2003 pin definition diagram

Maximum rating

Table 1 Maximum Ratings

symbol	parameters	maximum rating	unit
Vo	The output voltage	50	V
Vin	Input voltage	30	V
Ic	Output current	500	mA
lb	Input Current	25	mA

Circuit schematic diagram

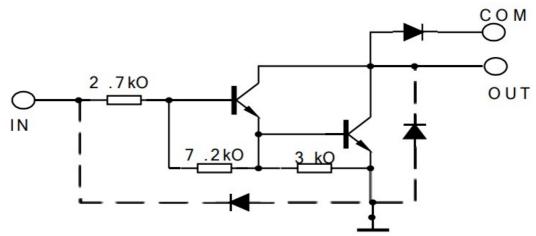


Figure 3 ULN2003 circuit schematic diagram

Electrical parameters

Table 2 Test electrical parameters

Symbol	Parameter Desc ription	Test Conditions	Min.	Тур.	Max.	unit	Test chart
ICEX	Output leakage current	VCE=50V	_	_	50.0	μΑ	Figure 1a.
VCE(sat)	Collector-emitter saturation voltag e drop	I _C =100mA I _B =250μA	_	0.9	1.1	V	Figure 2.
		I _C =200mA I _B =350μA	_	1.1	1.3		
		I _C =350mA I _B =500μA	_	1.3	1.6		
li(on)	Input turn-on cur rent	Vi=3.85V	_	0.93	1.35	mA	Figure 3.
you(he)	Input turn-on vol tage	V _{CE} =2.0V I _C =200mA V _{CE} =2.0V I _C =250mA V _{CE} =2.0V I _C =300mA	_	_	2.4 2.7 3.0	V	Figure 5.
I _R	Diode leakage c urrent	VR=50V	-4.0	_	50.0	μA	Figure 6.
V _F	Diode forward v oltage drop	I _F =350mA	_	1.7	2	V	Figure 7.
ICEX- 1V	Output leakage current	V _{CE} =50V V _i =1V	-5	_	80	μΑ	Figure 1b.

Test circuit diagram

Figure 1a.

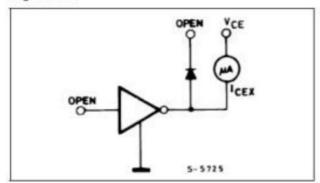


Figure 1b.

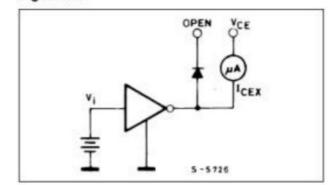


Figure 2.

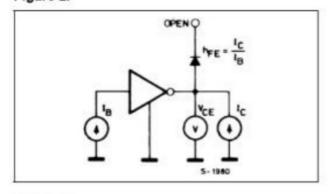


Figure 3.

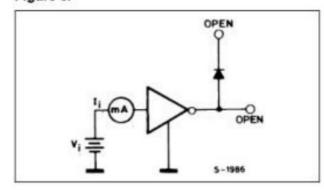


Figure 4.

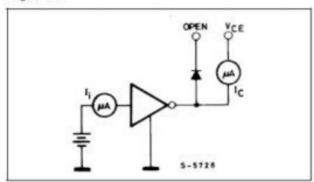


Figure 5.

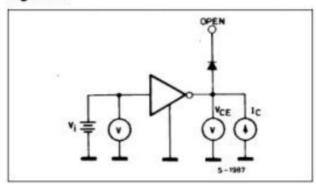


Figure 6.

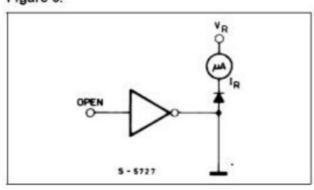
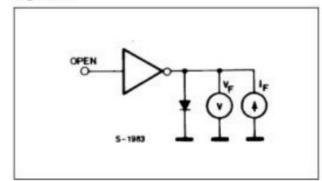


Figure 7.



Characteristic curve diagram

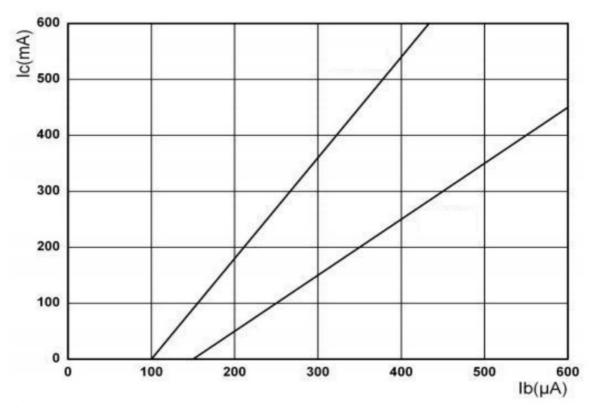


Figure 4 Output voltage and input current characteristic curve chart

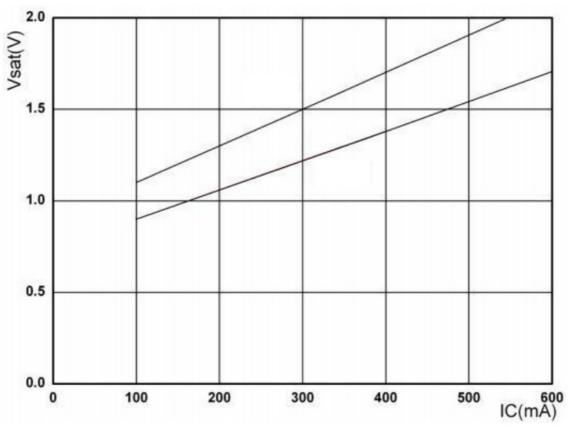
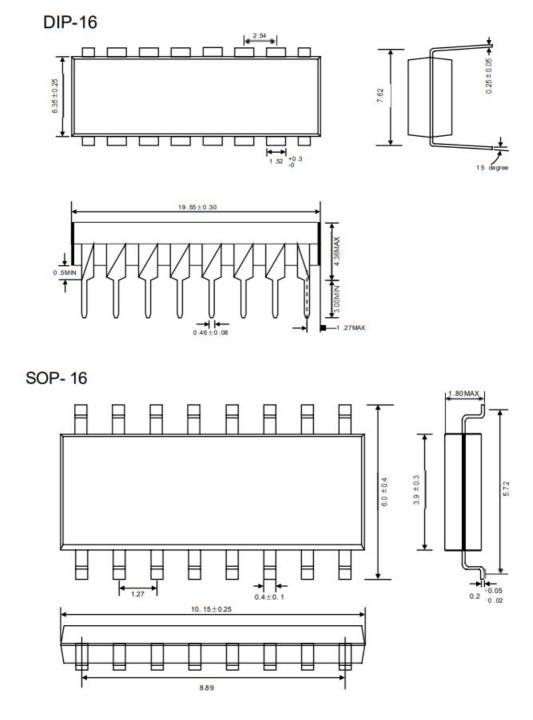


Figure 5 Saturation voltage drop and output voltage characteristic curve chart

Package information and dimensions



Note: Dimensions are in MM

Figure 6 ULN2003 package and size diagram

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Documents / Resources



<u>HUAXUANYANG ULN2003 Darlington Transistor Array</u> [pdf] Instructions JSMICRO, ULN2003 Darlington Transistor Array, ULN2003, Darlington Transistor Array, Transis tor Array, Array

References

- • MOS ESD TVS,
- User Manual

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